SMD Type Transistors

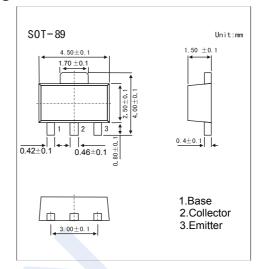
PNP Transistor

2SB1188

■ Features

Low VCE(sat).

 $V_{CE(sat)} = -0.5V (Typ.)$ (Ic/IB = -2A / -0.2A)



■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	Rating	Unit
Collector-base Voltage	Vсво	-40	V
Collector-emitter Voltage	VCEO	-32	V
Emitter-base Voltage	VEBO	-5	٧
Collector current	lc lc	-2	А
	ICP*	-3	А
Collector power dissipation	Pc	0.5	W
Jumction temperature	Tj	150	$^{\circ}$
Storage temperature	Tstg	-55 to +150	$^{\circ}$

^{*} PW=100ms

■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Collector-base breakdown voltae	ВУсво	Ic = -50 uA	-40			V
Collector-emitter breakdown voltage	BVceo	Ic = -1mA	-32			V
Emitter-base breakdown voltage	ВVево	IE = -50 μ A	-5			V
Collector cutoff current	Ісво	Vcb = -20V			-1	uA
Emitter cutoff current	ІЕВО	VEB = -4V			-1	uA
Collector-Emitter Saturation Voltage	VCE(sat)	Ic = -2A , IB = -0.2A		-0.5	-0.8	V
DC current transfer ratio	hFE	Vce = -3V , Ic = -0.5A	82		390	
Output Capacitance	Cob	VcB = -10V , IE = 0, f = 1MHz		50		pF
Transition frequency	f⊤	Vce = -5V , Ie = 0.5A , f = 30MHz		100		MHz

■ hFE Classification

Marking	BC*			
Rank	Р	Q	R	
hFE	82~180	120~270	180~390	

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